

MITSUBISHI IGBT MODULES
CM50TL-24NF

HIGH POWER SWITCHING USE

CM50TL-24NF



- IC 50A
- VCES 1200V
- Insulated Type
- 6-elements in a pack

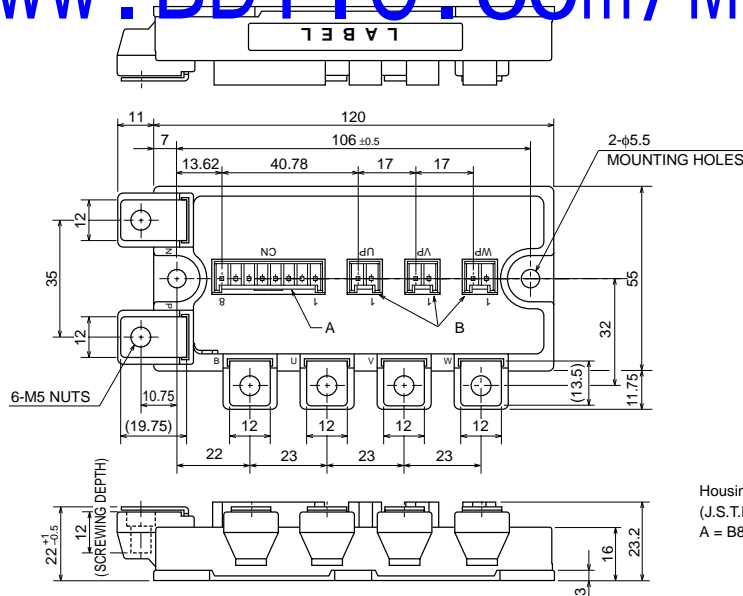
APPLICATION

AC drive inverters & Servo controls, etc

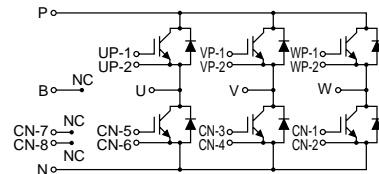
OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm

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Housing Type of A and B
 (J.S.T.Mfg.Co.Ltd)
 A = B8P-VH-FB-B, B = B2P-VH-FB-B



CIRCUIT DIAGRAM

ABSOLUTE MAXIMUM RATINGS (T_j = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CE} S	Collector-emitter voltage	G-E Short	1200	V
V _{GE} S	Gate-emitter voltage	C-E Short	±20	V
I _C	Collector current	DC, T _c = 94°C ^{*1}	50	A
I _{CM}		Pulse (Note 2)	100	A
I _E (Note 1)	Emitter current		50	A
I _{EM} (Note 1)		Pulse (Note 2)	100	A
P _C (Note 3)	Maximum collector dissipation	T _c = 25°C	390	W
T _j	Junction temperature		-40 ~ +150	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
V _{iso}	Isolation voltage	Main Terminal to base plate, AC 1 min.	2500	V
—	Torque strength	Main Terminal M5	2.5 ~ 3.5	N•m
—		Mounting holes M5	2.5 ~ 3.5	N•m
—	Weight	Typical value	350	g

ELECTRICAL CHARACTERISTICS (T_j = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I _{CE} S	Collector cutoff current	V _{CE} = V _{CE} S, V _{GE} = 0V	—	—	1	mA
V _{GE(th)}	Gate-emitter threshold voltage	I _C = 5.0mA, V _{CE} = 10V	6	7	8	V
I _{GES}	Gate leakage current	V _{GE} = V _{GES} , V _{CE} = 0V	—	—	0.5	μA
V _{CE(sat)}	Collector-emitter saturation voltage	I _C = 50A, V _{GE} = 15V T _j = 25°C T _j = 125°C	—	2.1 2.4	3.0	V
C _{ies}	Input capacitance	V _{CE} = -10V V _{GE} = 0V	—	—	8.5	nF
C _{oes}	Output capacitance	V _{CE} = -10V V _{GE} = 0V	—	—	75	nF
C _{res}	Reverse transfer capacitance		—	—	0.17	nF
Q _G	Total gate charge	V _{CC} = 600V, I _C = 50A, V _{GE} = 15V	—	250	—	nC
t _{d(on)}	Turn-on delay time		—	—	100	ns
t _r	Turn-on rise time	V _{CC} = 600V, I _C = 50A	—	—	50	ns
t _{d(off)}	Turn-off delay time	V _{GE1} = V _{GE2} = 15V	—	—	300	ns
t _f	Turn-off fall time	RG = 6.3Ω, Inductive load switching operation	—	—	350	ns
t _{rr} (Note 1)	Reverse recovery time	I _E = 50A	—	—	100	ns
Q _{rr} (Note 1)	Reverse recovery charge		—	2	—	μC
V _{EC} (Note 1)	Emitter-collector voltage	I _E = 50A, V _{GE} = 0V	—	—	3.8	V
R _{th(j-c)Q}	Thermal resistance	IGBT part (1/6 module) ^{*1}	—	—	0.32	°C/W
R _{th(j-c)R}		FWDi part (1/6 module) ^{*1}	—	—	0.43	°C/W
R _{th(c-f)}	Contact thermal resistance	Case to fin, Thermal compound Applied (1/6 module) ^{*2}	—	0.085	—	°C/W
R _G	External gate resistance		6.3	—	96	Ω

*1 : T_c measured point is just under the chips.

If you use this value, R_{th(f-a)} should be measured just under the chips.

*2 : Typical value is measured by using Shin-etsu Silicone "G-746".

Note 1. I_E, V_{EC}, t_{rr} & Q_{rr} represent characteristics of the anti-parallel, emitter to collector free-wheel diode (FWDi).

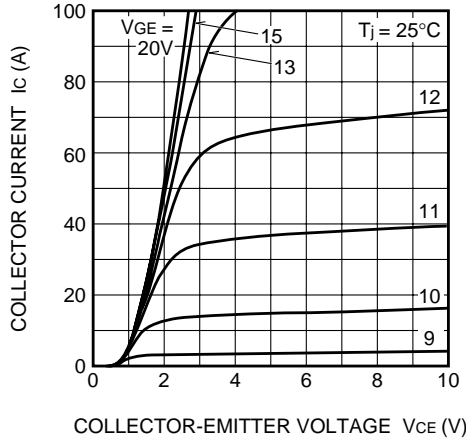
2. Pulse width and repetition rate should be such that the device junction temp. (T_j) does not exceed T_{jmax} rating.

3. Junction temperature (T_j) should not increase beyond 150°C.

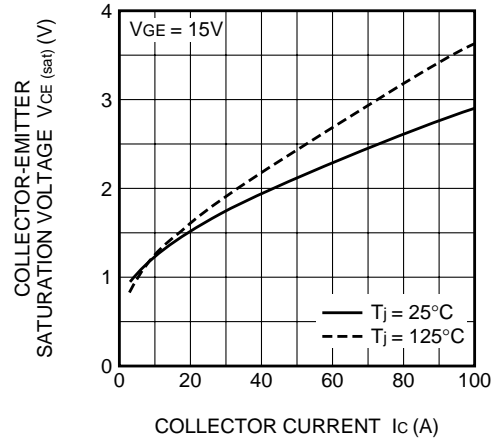
4. Pulse width and repetition rate should be such as to cause negligible temperature rise.

PERFORMANCE CURVES

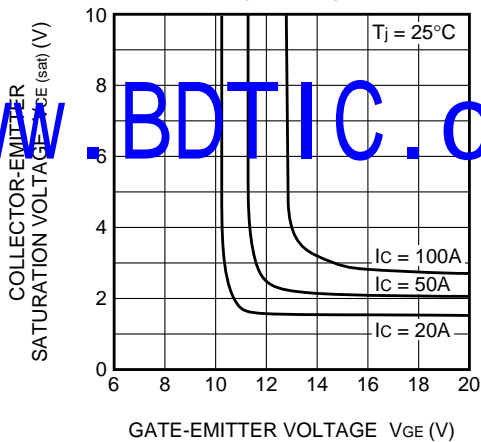
OUTPUT CHARACTERISTICS (TYPICAL)



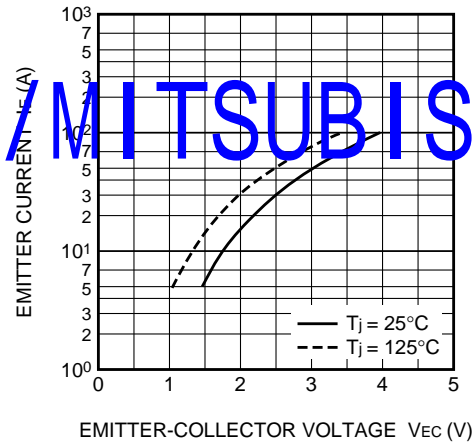
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



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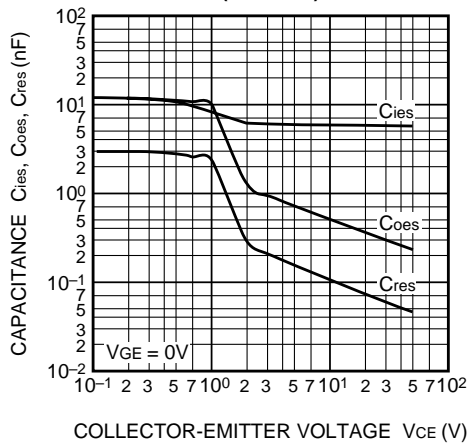


FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)

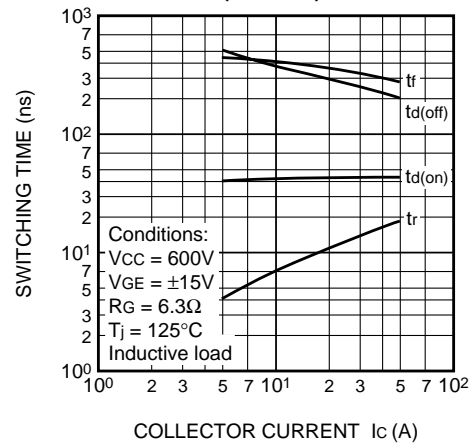


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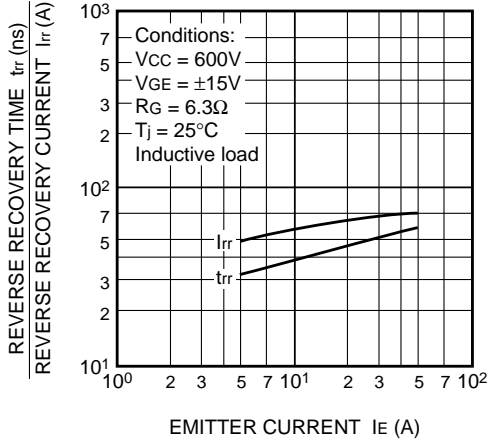
CAPACITANCE-VCE CHARACTERISTICS (TYPICAL)



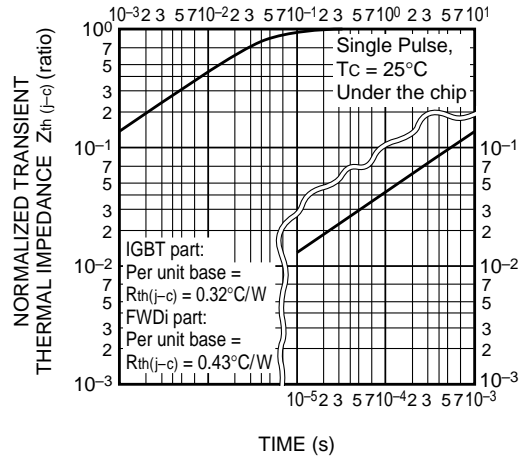
HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)



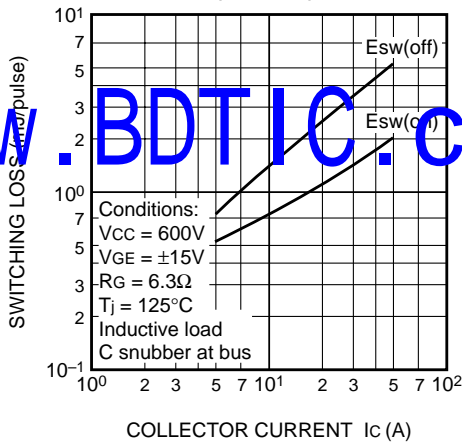
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



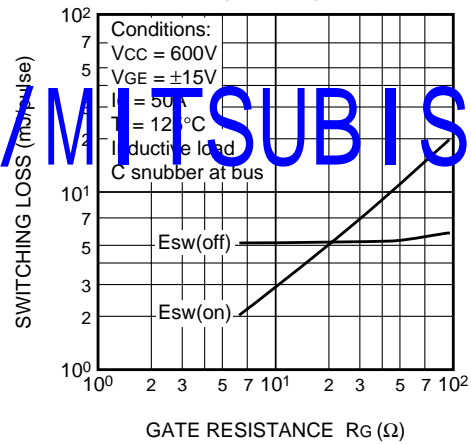
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT part & FWDi part)



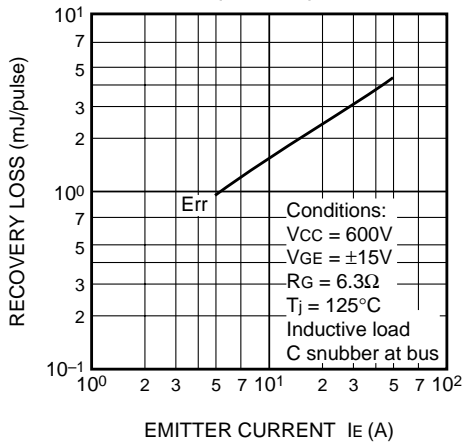
SWITCHING LOSS vs. COLLECTOR CURRENT (TYPICAL)



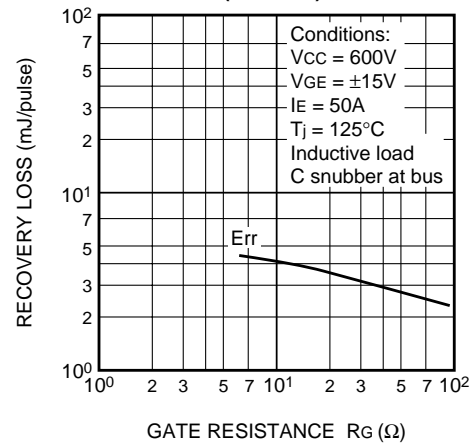
SWITCHING LOSS vs. GATE RESISTANCE (TYPICAL)



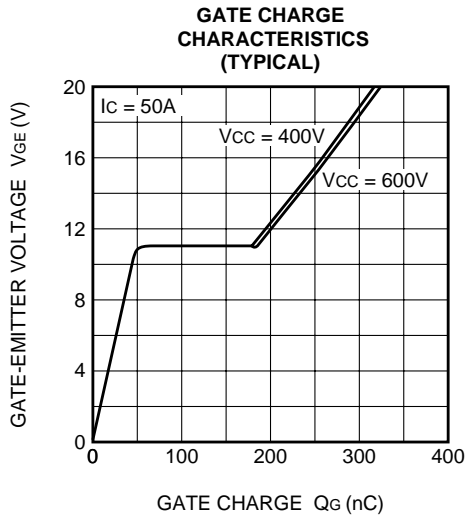
RECOVERY LOSS vs. IE (TYPICAL)



RECOVERY LOSS vs. GATE RESISTANCE (TYPICAL)



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